Supporting information for:

## Insight on shallow trap states introduced photocathodic performance in n-type polymer photocatalysts

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XRD patterns were collected by a D8 Bruker Diffractometer. The UV-Vis absorption spectra were collected using a Shimadzu UV-Vis 2550 spectrophotometer fitted with an integrating sphere using BaSO₄ as the reference material. XPS measurements were done on a Thermoscientific XPS K-alpha surface analysis machine using an AI source. Analysis was performed on the Casa XPS software. SEM images were taken by a JEOL JSM-7401F Scanning Electron Microscope. BET measurements were performed by a Tri Star II. NMR spectra were performed with a solid state NMR spectrometer, Ascend<sup>™</sup>, 300WB, Bruker. PL spectra were collected by a Renishaw InVia Raman Microscope (325nm).



Figure S1. XPS C1s spectra of all samples

Table S1. The ratio of C-O bond to N=C-N bond and C to N ratio in all samples

Sample	Ratio of C-O/N=C-C	C <sub>x</sub> N <sub>y</sub>
ref-g-C <sub>3</sub> N <sub>4</sub>	0.047±0.007	C <sub>3</sub> N <sub>4.10±0.03</sub>
def-g-C₃N₄-1	0.58±0.16	C <sub>3</sub> N <sub>3.18±0.12</sub>
def-g-C₃N₄-2	0.33±0.07	C <sub>3</sub> N <sub>3.65±0.04</sub>
def-g-C <sub>3</sub> N <sub>4</sub> -5	0.13±0.01	C <sub>3</sub> N <sub>3.61±0.01</sub>

Table S2 Surface area of def-g-C<sub>3</sub>N<sub>4</sub>-1, def-g-C<sub>3</sub>N<sub>4</sub>-2 and def-g-C<sub>3</sub>N<sub>4</sub>-5 samples determined by BET measurements.

	Surface area (m²/g)	
g-C <sub>3</sub> N <sub>4</sub>	10.9	
def-g-C <sub>3</sub> N <sub>4</sub> -1	12.9	
def-g-C <sub>3</sub> N <sub>4</sub> -2	13.4	
def-g-C <sub>3</sub> N <sub>4</sub> -5	18.5	



Figure S2 BET measurement of g-C<sub>3</sub>N<sub>4</sub>, def-g-C<sub>3</sub>N<sub>4</sub>-1, def-g-C<sub>3</sub>N<sub>4</sub>-2 and def-g-C<sub>3</sub>N<sub>4</sub>-5 samples



Figure S3. <sup>1</sup>H MAS solid state NMR spectra of (a) reference bulk-g-C<sub>3</sub>N<sub>4</sub> and (b) def-g-C<sub>3</sub>N<sub>4</sub>-5, as well as <sup>13</sup>C CP MAS solid state NMR spectra of (c) reference bulk-g-C<sub>3</sub>N<sub>4</sub> and (d) def-g-C<sub>3</sub>N<sub>4</sub>-5.

<sup>1</sup>H Solid state NMR spectrum of ref-g-C<sub>3</sub>N<sub>4</sub> contains two main peaks at 8.9 ppm and 4.2 ppm, which can be attributed to the chemical shifts of  $-NH_x$  ending group and residual water, respectively.<sup>1</sup> An additional clear peak locating at 4.5 ppm is present in def-g-C<sub>3</sub>N<sub>4</sub>-5 sample and can be ascribed to the formation C-OH bonds.<sup>1</sup> <sup>13</sup>C solid state NMR spectra of these two samples show two similar peaks at 156.8 ppm and 164.7 ppm, which has been assigned to C-[N]<sub>3</sub> and CN<sub>2</sub>(NH<sub>2</sub>) groups, respectively<sup>2</sup>



Figure S4 XPS N1s spectra of all g-C<sub>3</sub>N<sub>4</sub> samples

Table S3 Percentage breakdown of different bonds and ratios of bonds within the N1s spectra

	C=N-C (sp <sup>2</sup> )	N-[C] <sub>3</sub> (sp <sup>3</sup> )	C-NH <sub>x</sub>	sp <sup>2</sup> to sum of sp <sup>3</sup> and
Binding Energy (eV)	398.7	399.9	401.0	C-NH <sub>x</sub>
ref-g-C <sub>3</sub> N <sub>4</sub>	74.2%	15.7%	10.2%	2.9
def-g-C <sub>3</sub> N <sub>4</sub> -1	63.8%	20.9%	15.3%	1.8
def-g-C <sub>3</sub> N <sub>4</sub> -2	66.3%	18.2%	15.5%	2.0
def-g-C <sub>3</sub> N <sub>4</sub> -5	72.0%	16.5%	11.5%	2.6



Figure S5. (a) UV-vis spectra, (b) Tauc plots and (c) XPS valence band spectra of ref-g-C<sub>3</sub>N<sub>4</sub>, def-g-C<sub>3</sub>N<sub>4</sub>-1, def-g-C<sub>3</sub>N<sub>4</sub>-2 and def-g-C<sub>3</sub>N<sub>4</sub>-5 films



Figure S6 Chopped light-response of bare FTO substrate.



Figure S7. SEM images of (a) ref-g- $C_3N_4$ , (b) def-g- $C_3N_4$ -1, (c) def-g- $C_3N_4$ -2 and (d) def-g- $C_3N_4$ -5 films



Figure S8. determination of average electron lifetime of (a) ref-g-C<sub>3</sub>N<sub>4</sub> and (b) def-g-C<sub>3</sub>N<sub>4</sub>-5 films



Figure S9 (a-c) Mott-schottky plots of ref-g-C<sub>3</sub>N<sub>4</sub> electrode at 500 Hz, 1000 Hz and 2000 Hz with 0% - 100% illumination; (d-f) Mott-schottky plots of def-g-C<sub>3</sub>N<sub>4</sub>-5 electrode at 1 KHz with 0% - 100% illumination;

Table S4 Carrier density N<sub>D</sub> and depletion layer width of ref-g-C<sub>3</sub>N<sub>4</sub> and def-g-C<sub>3</sub>N<sub>4</sub>-5 samples

	Measured slope (1000	N <sub>D</sub> ( $\varepsilon_r$ =7.7)	$W_{sc}$ ( $\epsilon_r = 7.7$ ;
	Hz)		0V vs RHE)
ref-g-C₃N₄ dark	1.57*10 <sup>13</sup>	1.2*10 <sup>18</sup> (cm <sup>-3</sup> )	22 nm
10% illumination	6.18*10 <sup>12</sup>	3.1*10 <sup>18</sup> (cm <sup>-3</sup> )	/
100% illumination	6.13*10 <sup>12</sup>	3.1*10 <sup>18</sup> (cm <sup>-3</sup> )	/
def-g-C <sub>3</sub> N <sub>4</sub> -5	1.10*10 <sup>10</sup>	1.7*10 <sup>21</sup> (cm <sup>-3</sup> )	0.4 nm
10% illumination	1.03*10 <sup>10</sup>	1.8*10 <sup>21</sup> (cm <sup>-3</sup> )	/
100% illumination	0.98*10 <sup>10</sup>	1.9*10 <sup>21</sup> (cm <sup>-3</sup> )	/

$$\frac{1}{C^2} = \frac{2}{\varepsilon \varepsilon_0 A^2 e N_D} (V - V_{fb} - \frac{k_B T}{e})$$

$$slope = \frac{2}{\varepsilon \varepsilon_0 A^2 e N_D}$$

$$W_{sc} = \sqrt{\frac{2\varepsilon_0 \varepsilon_r}{e N_D} (V - V_{fb} - \frac{k_B T}{e})}$$

 $\varepsilon_0$  is the vacuum permittivity: 8.854187817×10<sup>-14</sup> F/cm,  $\varepsilon_r$  is the static dielectric constant: it is 7.7 for c-C<sub>3</sub>N<sub>4</sub><sup>3</sup> and current not available for g-C<sub>3</sub>N<sub>4</sub>; A is the area: 1 cm<sup>2</sup>; e is the electron charge: 1.6×10<sup>-19</sup>C.

Table S5. Analysis of impedance plots of ref-g-C<sub>3</sub>N<sub>4</sub> and def-g-C<sub>3</sub>N<sub>4</sub>-5;  $R_s$  is the system resistance,  $R_{ct}$  is the charge transfer resistance, CPE is the constant phase element representing the double layer capacitor.

	R <sub>s</sub> (Ω cm²)	$R_{ct} / (\Omega \ cm^2)$	CPE (S <sup>n</sup> Ω <sup>-1</sup> cm <sup>-2</sup> )	Ν
ref-g-C₃N₄	218 (±116.93%)	1.3 * 10 <sup>5</sup> (±0.46%)	8.1 * 10 <sup>-7</sup> (±1.26%)	0.94 (±0.49%)
def-g-C <sub>3</sub> N <sub>4</sub> -5	49 (±27.35%)	5.6 * 10 <sup>3</sup> (±0.86%)	4.5 * 10 <sup>-5</sup> (±1.71%)	0.85 (±0.90%)



Figure S10. Normalised photoluminescence spectra of ref-g- $C_3N_4$ , def-g- $C_3N_4$ -1, def-g- $C_3N_4$ -2 and def-g- $C_3N_4$ -5 samples after 325 nm excitation, recorded using a Renishaw InVia Raman Microscope (325nm)

Photoluminescence (PL) spectroscopy was undertaken using a 325 nm laser probe. The PL signal peaks around 450 and 500 nm are assigned to the  $\pi-\pi^*$  transitions and  $n-\pi^*$  emission, respectively.<sup>4</sup>



Figure S11 TAS spectra of def-g-C<sub>3</sub>N<sub>4</sub>-1 sample in N<sub>2</sub>, (N<sub>2</sub>-flushed) water and (N<sub>2</sub>-flushed) 2mM AgNO<sub>3</sub> solution.



Figure S12. OCVD curve (black) and fitted analysis (red) of H<sub>2</sub>O<sub>2</sub> treated ref-g-C<sub>3</sub>N<sub>4</sub> sample

## Reference

1. Zhang, Q.; Chen, P.; Tan, C.; Chen, T.; Zhuo, M.; Xie, Z.; Wang, F.; Liu, H.; Cai, Z.; Liu, G., A photocatalytic degradation strategy of PPCPs by a heptazine-based CN organic polymer (OCN) under visible light. *Environmental Science: Nano* **2018**, *5* (10), 2325-2336.

2. Wang, Y.; Bayazit, M. K.; Moniz, S. J.; Ruan, Q.; Lau, C. C.; Martsinovich, N.; Tang, J., Linkercontrolled polymeric photocatalyst for highly efficient hydrogen evolution from water. *Energy & Environmental Science* **2017**, *10* (7), 1643-1651.

3. Mo, S.-D.; Ouyang, L.; Ching, W.; Tanaka, I.; Koyama, Y.; Riedel, R., Interesting physical properties of the new spinel phase of Si 3 N 4 and C 3 N 4. *Physical Review Letters* **1999**, *83* (24), 5046.

4. Jorge, A. B.; Martin, D. J.; Dhanoa, M. T.; Rahman, A. S.; Makwana, N.; Tang, J.; Sella, A.; Corà, F.; Firth, S.; Darr, J. A., H2 and O2 evolution from water half-splitting reactions by graphitic carbon nitride materials. *The Journal of Physical Chemistry C* **2013**, *117* (14), 7178-7185.